
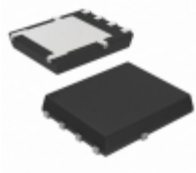
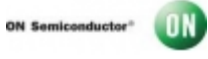
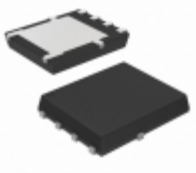
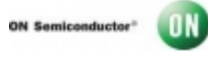
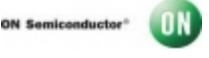
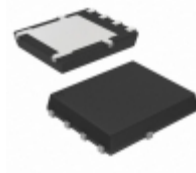
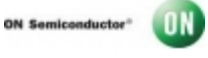
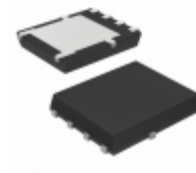
	<h2 style="color: red;">NTMFS4C13NT1G</h2>
	<p>Hersteller-Teilenummer: NTMFS4C13NT1G</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 30V 38A SO8FL</p> <p>Datenblätter:  NTMFS4C13NT1G.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 3645 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NTMFS4C13NT1G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 30V 38A SO8FL
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	3645 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	8-PowerTDFN
Supplier Device-Gehäuse	5-DFN (5x6) (8-SOFL)
Verlustleistung (max)	750mW (Ta)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	7.2A (Ta), 38A (Tc)
Rds On (Max) @ Id, Vgs	9.1 mOhm @ 30A, 10V
VGS (th) (Max) @ Id	2.1V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	15.2nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	770pF @ 15V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)

NTMFS4C13NT1G ist neu im Original, Suche NTMFS4C13NT1G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTMFS4C13NT1G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTMFS4C13NT1G: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NTMFS4C10NT1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 8.2A SO8FL</p>	 <p>NTMFS4C35N AMI Semiconductor / ON Semiconductor NTMFS4C35N ON</p>	 <p>NTMFS4C302NT1G AMI Semiconductor / ON Semiconductor NFET SO8FL 30V 1.15MO</p>	 <p>NTMFS4C10NT3G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 8.2A SO8FL</p>
 <p>NTMFS4C10NBT3G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 16.4A 46A 5DFN</p>	 <p>NTMFS4C13NT3G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 38A SO8FL</p>	 <p>NTMFS4C10NBT1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 16.4A 46A 5DFN</p>	 <p>NTMFS4C10NT1G-001 AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 8.2A SO8FL</p>

heiße Teile

Mehr

NTMFS4935NT1G	NTMFS4936N	NTMFS4936NT1G	NTMFS4937N	NTMFS4937NT1G
NTMFS4939NT1G	NTMFS4939NT3G	NTMFS4941NT1G	NTMFS4943NT1G	NTMFS4945NT1G
NTMFS4946N	NTMFS4946NT1G	NTMFS4955NT1G	NTMFS4982NFT1G	NTMFS4983NBFTG
NTMFS4983NFT1G	NTMFS4985NFT1G	NTMFS4C05N	NTMFS4C05NT1G	NTMFS4C06N
NTMFS4C06NT1G	NTMFS4C08NT1G	NTMFS4C09NAT1G	NTMFS4C09NT1G	NTMFS4C10NT1G
NTMFS4C35N	NTMFS4C55NT1G	NTMFS4C58NT1G	NTMFS4C800NT1G	NTMFS5844NLT1G
NTMFS5C404NLT1G	NTMFS5C612NLT1G	NTMFS5C628NLT1G	NTMFS5C646NLT1G	NTMFS5C670NLT1G
NTMS10P02	NTMS10P02R2	NTMS10P02R2G	NTMS3P03R2	NTMS3P03R2G
NTMS4101PR2G	NTMS4105NR2G	NTMS4107NR2G	NTMS4176PR2G	NTMS4177P
NTMS4177PR2G	NTMS4404NR2G	NTMS4503NR2G	NTMS4700NR	NTMS4700NR2G

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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